

INCHANGE SEMICONDUCTOR

isc Silicon PNP Darlington Power Transistor

2SB1254

DESCRIPTION

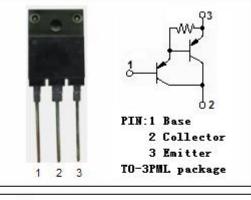
- · High DC Current Gain-
 - : h_{FE}= 5000(Min)@I_C= -6A
- Low-Collector Saturation Voltage-
- : V_{CE(sat)}= -2.5V(Max.)@I_C= -6A
- Complement to Type 2SD1894
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

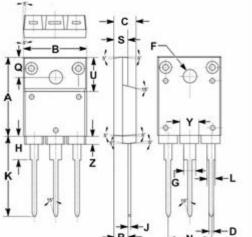
APPLICATIONS

· Designed for power amplifier applications

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-160	V	
V _{CEO}	Collector-Emitter Voltage	-140	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous	-7	A	
Ісм	Collector Current-Peak	-12	A	
Pc	Collector Power Dissipation @ $T_C=25^{\circ}C$	70	W	
	Collector Power Dissipation @ T _a =25°C	3		
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	°C	

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)





	mm	
DIM	MIN	MAX
Α	19.90	20.10
В	15.75	16.10
С	5.50	5.70
D	0.90	1.10
E	3.30	3.50
G	2.90	3.20
Η	5.90	6.10
J	0.595	0.70
κ	21.10	22.50
Ľ	1.90	2.25
N	10.80	11.00
Q	4.90	5.10
R	3.75	3.95
S	3.20	3.60
U	9.90	10.10
Y	4.20	4.90
Z	1.90	2.10

isc website: <u>www.iscsemi.com</u>



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -30mA; I _B = 0	-140			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -6A; I _B = -6mA			-2.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = -6A; I _B = -6mA			-3.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -160V; I _E = 0			-100	μ Α
ICEO	Collector Cutoff Current	V _{CE} = -140V; I _B = 0			-100	μ Α
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-100	μ Α
h _{FE-1}	DC Current Gain	I _C = -1A; V _{CE} = -5V	2000			
h _{FE-2}	DC Current Gain	I _C = -6A; V _{CE} = -5V	5000		30000	

h_{FE-2} Classifications

Q	Р	
5000-15000	8000-30000	

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